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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/764,750	01/26/2004	Hsiang-Lan Lung	MXIC-P910329	8735	
75	90 07/27/2005		EXAMINER		
Kenton R. Mullins Stout, Uxa, Buyan & Mullins, LLP 4 Venture, Suite 300			NGO, NGAN V		
			ART UNIT	PAPER NUMBER	
Irvine, CA 920			2818		
			DATE MAILED: 07/27/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

			#K
•	Application No.	Applicant(s)	
	10/764,750	LUNG ET AL	
Office Action Summary	Examiner	Art Unit	
	Ngan Ngo	2818	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the c	correspondence addre	ess
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reg. If NO period for reply is specified above, the maximum statutory period.  - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).		nely filed s will be considered timely. the mailing date of this comm D (35 U.S.C. § 133).	nunication.
Status			
1) Responsive to communication(s) filed on			
• • • • • • • • • • • • • • • • • • • •	s action is non-final.		
3) Since this application is in condition for allows closed in accordance with the practice under	· · · · · · · · · · · · · · · · · · ·		erits is
Disposition of Claims			
4) Claim(s) 1-14 is/are pending in the application 4a) Of the above claim(s) is/are withdra 5) Claim(s) is/are allowed. 6) Claim(s) 1-14 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/or claim(s) are subject to restriction and/or claim(s) are subject to by the Examination of the content of	er. cepted or b) objected to by the led drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).	1 121 <i>(</i> d)
11) The oath or declaration is objected to by the E			• •
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the attached detailed Office action for a list	nts have been received. Its have been received in Applicationity documents have been received in Application (PCT Rule 17.2(a)).	on No ed in this National St	age
Attachment(s)	0 D lates is 2000	(DTO 412)	
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> <li>Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date</li> </ol>	4) Interview Summary Paper No(s)/Mail Da  5) Notice of Informal P  6) Other:	ate	52)

Application/Control Number: 10/764,750

**Art Unit: 2818** 

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1-4, 6-11, 13, and 14 are rejected under 35 U.S.C. 102(e) as being anticipated by Hush (US-6873538 B2).

Hush discloses a memory cell comprising a chalcogenide random access memory cell and a CMOS circuit operative to access the CRAM cell. Note lines 30-40 of column 3 and lines 6-10 of column 4 of Hush.

In re claims 2 and 3, Hush discloses the CRAM cell having cross-section area. No patentable weight is given to "thin film process" and "iso-etching process" because they are process limitation in the product claim. A "product by process" claim is directed to the product per se, no matter how actually made, In re Hirao, 190 USPQ 15 at 17(footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery, 186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); In re Marosi et al, 218 USPQ 289; and particularly In re Thorpe, 227 USPQ 964, all of which make it clear that it is the patentability of the final product per se which must be determined in a "product by process" claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in

Application/Control Number: 10/764,750

Art Unit: 2818

"product by process" claims or not. Note that applicant has the burden of proof in such cases, as the above caselaw makes clear.

In re claim 4, Hush discloses a chalcogenide structure (chalcogenide layer disposed between electrodes 150 and 152) in series with a semiconductor device (CMOS transistor 124)

In re claim 6, Hush discloses a selecting transistor operative to drive a current through the chalcogenide structure when enabled by a voltage at a gate terminal of the selecting transistor. See column 4, lines 20-45.

In re claims 7, 8, and 14, Hush discloses in figures 1 and 4 that the selecting transistor can be connected to word lines (110), drive lines, and bit lines (116).

The subject matter of claims 9-11 and 13 has been discussed above.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 5 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hush in view of Chen et al. (US 2004/0257854 A1).

Hush discloses all the subject matter discussed above; however, Hush does not teach the diodes driving current through the chalcogenide structure. Chen discloses in paragraph [0021] that a diode can be used to drive current through the chalcogenide structure instead of a transistor. Therefore, it would have been obvious to one of

Art Unit: 2818

ordinary skill in the art to use a diode to drive a current through the chalcogenide structure as taught by Chen.

The other references are cited to show other structures pertinent to Applicants' disclosure.

Any inquiry concerning this communication should be directed to Examiner Ngan Ngo at telephone number (571) 272-1711. The fax phone number for the organization where this application or proceeding is assigned is (571)-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Ngan Van Ngo Primary Examiner

Ngan Ngo

July 24, 2005